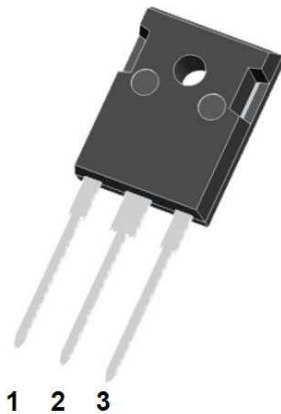


Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-247AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR60200PT-B1-W5029HF
Device marking code			MBR60200PT
Repetitive peak reverse voltage	VRRM	V	200
Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% duty cycle, Tc (FIG 1)	IFAV	A	60
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Tj=25°C	IFSM	A	420
Current Squared Time @1ms≤t≤8.3ms Tj=25°C	I ² t	A ² s	732
Storage temperature	TSTG	°C	-55 ~+175
Junction temperature	TJ	°C	-55 ~+175

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	V _F	V	I _{FM} =30.0A T _j =25°C	-	0.86	0.95
			I _{FM} =30.0A T _j =125°C	-	0.75	0.82
DC reverse current at rated DC blocking voltage per diode,@ VRM=VRRM	I _{RRM}	mA	V _{RM} =V _{RRM} T _j =25°C	-	-	0.1
			V _{RM} =V _{RRM} T _j =125°C	-	-	20
Junction capacitance	C _j	pF	1MHZ and Applied Revers Voltage of 4.0 V.D.C.	300	490	700

Note1:Pulse test:300uS pulse width,1% duty cycle

Note2:Pulse test:pulse width 40mS



MBR60200PT-B1-W5029HF

■ Thermal Characteristics (T_j=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBR60200PT-B1-W5029HF
Thermal Resistance	Between junction and ambient	R _{θJA}	°C/W	50.0
	Between junction and case	R _{θJC}	°C/W	1.0

■ Characteristics(Typical)

FIG1:I_o-T_c Curve

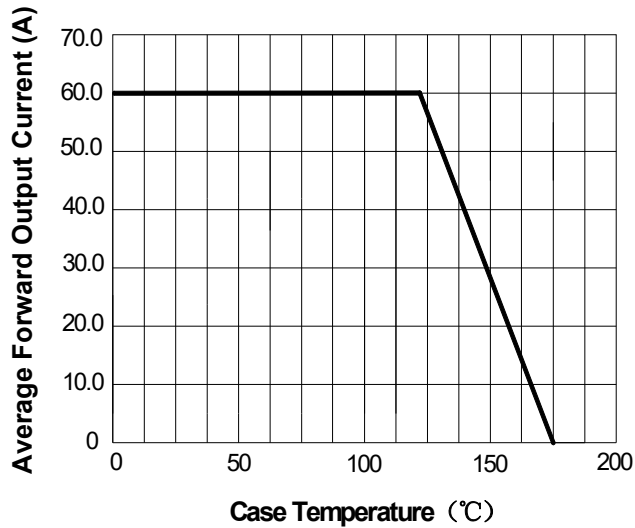


FIG2: Surge Forward Current Capability

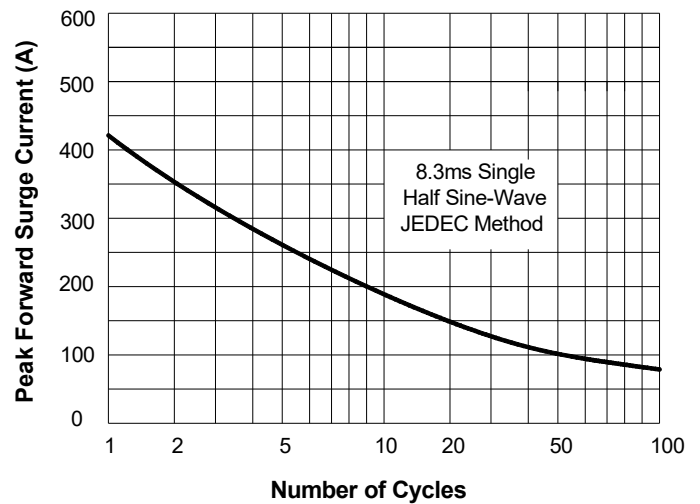


FIG3: Forward Voltage

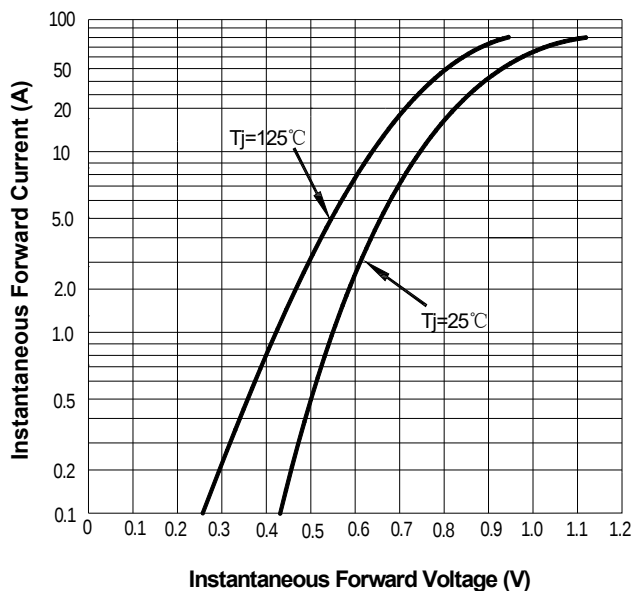
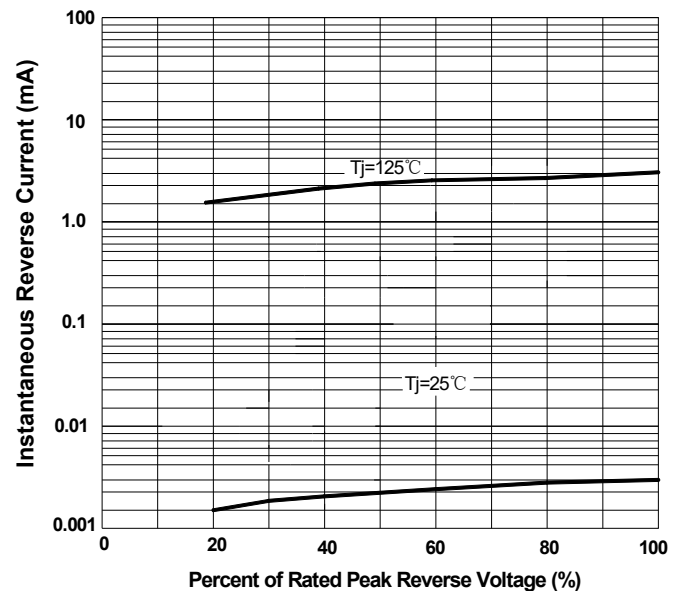


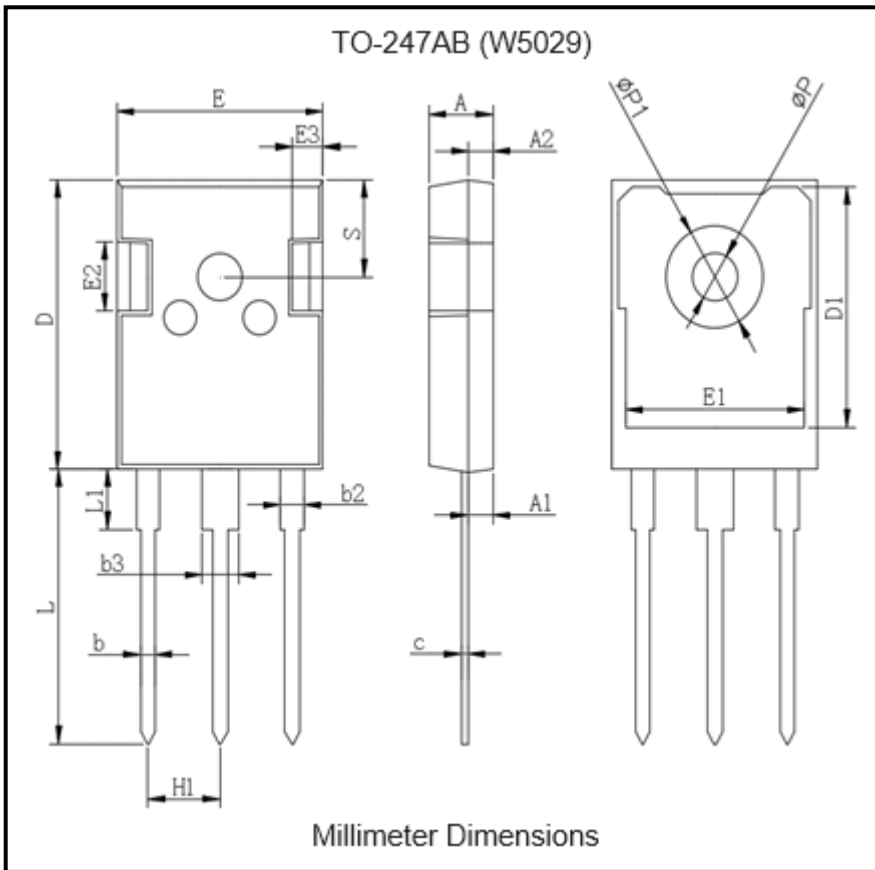
FIG4: Instantaneous Reverse Characteristics





MBR60200PT-B1-W5029HF

■ Outline Dimensions



TO-247AB (W5029)		
Dim	Min	Max
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.0	1.4
b2	-	2.25
b3	-	3.25
C	0.5	0.7
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.0	13.6
E2	4.80	5.20
E3	2.30	2.70
L	19.62	20.22
L1	-	4.30
ΦP	3.40	3.80
ΦP1	-	7.30
S	6.15TYP	
H1	5.44TYP	



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